Features

- MACOM PURE CARBIDE™ Amplifier Series
- Suitable for Linear & Saturated Applications
- CW & Pulsed Operation: 85 W Output Power
- Internally Pre-Matched
- 50 V Operation
- Compatible with MACOM Power Management Bias Controller/Sequencer MABC-11040

Applications

Military Radio Communications, RADAR, Avionics, Digital Cellular Infrastructure, RF Energy, and Test Instrumentation.

Description

The MAPC-A1101 is a high power GaN on Silicon Carbide HEMT D-mode amplifier suitable for DC - 3.5 GHz frequency operation. The device supports both CW and pulsed operation with output power levels of at least 85 W (49.3 dBm) in an air cavity ceramic package.

Typical Performance:

- Measured under load-pull at 2.5 dB compression, 100 µs pulse width, 10% duty cycle
- V_{DS} = 50 V, I_{DQ} = 130 mA, T_C = 25°C

Frequency (GHz)	Output Power ¹ (dBm)	Gain ² (dB)	η _D ²
0.9	49.9	25.0	72.5
1.4	1.4 50.0 21.7		72.6
2.0	49.8	16.5	66.1
2.5	50.6	17.2	64.8
3.0	3.0 50.1 16.5		67.6
3.5	49.7	15.7	70.5

• V_{DS} = 28 V, I_{DQ} = 130 mA, T_C = 25°C

Frequency (GHz)	Output Power ¹ (dBm)		
0.9	47.0	22.0	71.2
1.4	47.0	20.0	72.0
2.0	47.2	14.7	68.1
2.5	47.8	14.6	69.0
3.0	47.4	14.2	70.0
3.5	47.0	13.4	72.5

1. Load impedance tuned for maximum output power.

2. Load impedance tuned for maximum drain efficiency.

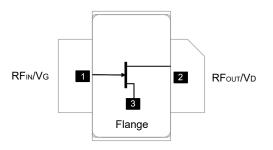
1 * Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



AC-360S-2

AC-360B-2

Functional Schematic



Pin Configuration

Pin #	Pin Name	Function
1	RF_IN / V_G	RF Input / Gate
2	RF_{OUT} / V_D	RF Output / Drain
3	3 Flange ³ Ground / Source	

3. The flange on the package bottom must be connected to RF, DC and thermal ground.

Ordering Information

Part Number	Package
MAPC-A1101-AS000	Bulk Quantity: Earless
MAPC-A1101-ASTR1	Tape and Reel: Earless
MAPC-A1101-ASSB1	Sample Board: Earless
MAPC-A1101-AB000	Bulk Quantity: Boltdown
MAPC-A1101-ABTR1	Tape and Reel: Boltdown

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MAPC-A1101

Rev. V5



MAPC-A1101

Rev. V5

RF Electrical Characteristics: $T_c = 25^{\circ}C$, $V_{DS} = 50 V$, $I_{DQ} = 130 mA$ Note: Performance in MACOM Evaluation Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	Pulsed ⁴ , 3.5 GHz	G _{SS}	-	17.0	-	dB
Power Gain	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	G _{SAT}	-	14.8	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	η_{SAT}	-	68.0	-	%
Saturated Output Power	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	P _{SAT}	-	49.0	-	dBm
Gain Variation (-25°C to +85°C)	Pulsed ⁴ , 3.5 GHz	ΔG	-	0.019	-	dB/°C
Power Variation (-25°C to +85°C)	Pulsed ⁴ , 3.5 GHz	$\Delta P2.5 dB$	-	0.008	-	dB/°C
Power Gain	Pulsed ⁴ , 3.5 GHz, P _{OUT} = 49.3 dBm	G _P	-	12.7	-	dB
Drain Efficiency	Pulsed ⁴ , 3.5 GHz, P _{OUT} = 49.3 dBm	η	-	70.2	-	%
Ruggedness: Output Mismatch	All phase angles	Ψ	VSWR = 10:1, No Damage		age	

RF Electrical Specifications: $T_A = 25^{\circ}C$, $V_{DS} = 50 V$, $I_{DQ} = 130 mA$ Note: Performance in MACOM Production Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Power Gain	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	G _{SAT}	14.0	15.1	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	η_{SAT}	55.0	60.0	-	%
Saturated Output Power	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	P _{SAT}	47.5	48.9	-	dBm
Power Gain	Pulsed ⁴ , 3.5 GHz, P _{IN} = 33 dBm	G _P	14.8	15.7	-	dB
Drain Efficiency	Pulsed ⁴ , 3.5 GHz, P _{IN} = 33 dBm	η	54.0	59.1	-	dB

4. Pulse details: 100 µs pulse width, 10% duty cycle.

DC Electrical Characteristics: T_A = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	V_{GS} = -8 V, V_{DS} = 130 V	I _{DLK}	-	-	8.9	mA
Gate-Source Leakage Current	V_{GS} = -8 V, V_{DS} = 0 V	I _{GLK}	-	-	8.9	mA
Gate Threshold Voltage	V _{DS} = 50 V, I _D = 8.88 mA	V _T	-3.6	-2.8	-	V
Gate Quiescent Voltage	V _{DS} = 50 V, I _D = 130 mA	V _{GSQ}	-3.2	-2.6	-2.2	V
On Resistance	V_{GS} = 2 V, I _D = 66.6 mA	R _{ON}	-	0.38	-	Ω
Maximum Drain Current	V_{DS} = 7 V pulsed, pulse width 300 µs	I _{D, MAX}	-	5.1	-	А

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MAPC-A1101

Rev. V5

Absolute Maximum Ratings^{5,6,7,8,9}

Parameter	Absolute Maximum		
Drain Source Voltage, V _{DS}	130 V		
Gate Source Voltage, V _{GS}	-10 to 3 V		
Gate Current, I _G	8.9 mA		
Storage Temperature Range	-65°C to +150°C		
Case Operating Temperature Range	-40°C to +85°C		
Channel Operating Temperature Range, T _{CH}	-40°C to +225°C		
Absolute Maximum Channel Temperature	+250°C		

5. Exceeding any one or combination of these limits may cause permanent damage to this device.

MACOM does not recommend sustained operation above maximum operating conditions. 6.

7.

8.

Operating at drain source voltage $V_{DS} < 55$ V will ensure MTTF > 2 x 10⁶ hours. Operating at nominal conditions with $T_{CH} \le 225^{\circ}$ C will ensure MTTF > 2 x 10⁶ hours. MTTF may be estimated by the expression MTTF (hours) = A $e^{[B + C/(T+273)]}$ where *T* is the channel temperature in degrees Celsius, A = 1, B = -38.215, and C = 26,343. 9

Thermal Characteristics¹⁰

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance using Finite Element Analysis	V _{DS} = 50 V, T _C = 85°C, T _{CH} = 225°C	$R_{\theta}(FEA)$	3.28	°C/W
Thermal Resistance using Infrared Measurement of Die Surface Temperature	V _{DS} = 50 V, T _C = 85°C, T _{CH} = 225°C	R _θ (IR)	2.56	°C/W

10. Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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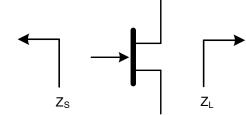
MAPC-A1101 Rev. V5

50 V Pulsed⁴ Load-Pull Performance Reference Plane at Device Leads

		Maximum Output Power						
			V _{DS} = 50 V, I _{DQ} = 130 mA, T _C = 25°C, P2.5dB					
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	Р _{оит} (dBm)	Р _{оит} (W)	η₀ (%)	AM/PM (°)	
0.9	0.76 + j1.85	9.76 + j1.80	22.6	49.9	96.8	61.5	0.1	
1.4	0.93 - j1.98	7.71 + j2.28	19.4	50.0	99.8	62.0	0.4	
2.0	1.77 - j4.86	5.43 + j1.16	14.9	49.8	94.6	55.1	-3.6	
2.5	1.79 - j8.49	5.30 - j0.02	15.3	50.6	116.0	55.6	-0.3	
2.7	2.29 - j10.5	5.34 - j0.27	15.2	50.1	101.4	56.0	0.8	
3.0	4.02 - j13.7	4.39 - j0.74	14.9	50.1	102.3	59.4	1.5	
3.5	14.6 - j15.5	3.74 - j2.47	13.8	49.7	94.2	57.9	-1.6	

		Maximum Drain Efficiency						
			V_{DS} = 50 V, I_{DQ} = 130 mA, T_{C} = 25°C, P2.5dB					
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	Р _{оит} (dBm)	P _{out} (W)	η₀ (%)	АМ/РМ (°)	
0.9	0.56 + j1.13	13.3 + j13.5	25.2	47.4	54.8	72.5	-0.8	
1.4	0.76 - j2.30	7.58 + j9.68	21.7	47.8	59.8	72.6	0.2	
2.0	1.55 - j4.95	3.90 + j5.30	16.5	47.7	59.4	66.1	-8.0	
2.5	1.49 - j8.55	4.00 + j3.21	17.2	49.3	84.3	64.8	-0.1	
2.7	1.90 - j10.3	3.60 + j2.83	17.2	48.6	72.8	64.7	-1.4	
3.0	3.30 - j13.6	2.92 + j1.45	16.5	48.6	73.1	67.6	-0.2	
3.5	13.1 - j17.3	2.07 - j0.28	15.8	47.7	58.7	70.5	-13.2	

Impedance Reference



Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.

Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.

11. Load Impedance for optimum output power.

12. Load Impedance for optimum efficiency.

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GaN Amplifier 50 V, 85 W DC - 3.5 GHz

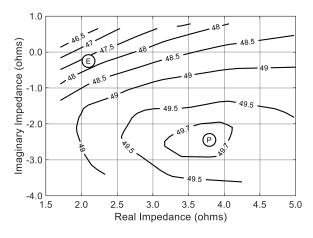
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MACOM PURE CARBIDE

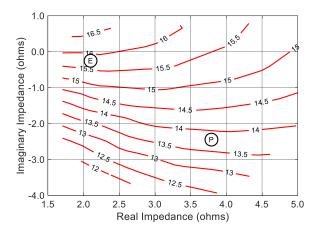
MAPC-A1101 Rev. V5

50 V Pulsed⁴ Load-Pull Performance @ 3.5 GHz

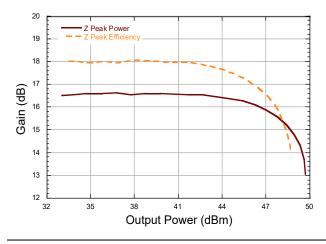
P2.5dB Loadpull Output Power Contours (dBm)



P2.5dB Loadpull Gain Contours (dB)

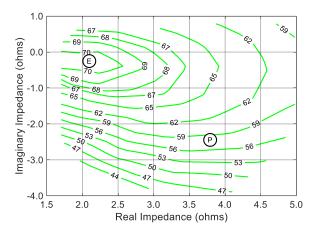


Gain vs. Output Power

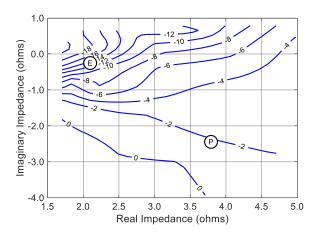


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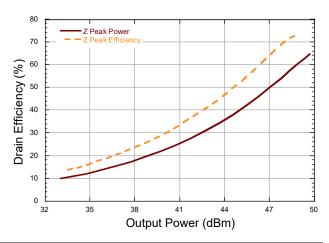
P2.5dB Loadpull Drain Efficiency Contours (%)



P2.5dB Loadpull AM/PM Contours (°)



Drain Efficiency vs. Output Power



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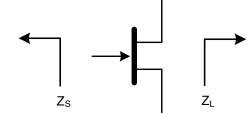
MAPC-A1101 Rev. V5

28 V Pulsed⁴ Load-Pull Performance Reference Plane at Device Leads

				Maximum Ou	tput Power		
		V _{DS} = 28 V, I _{DQ} = 130 mA, T _C = 25°C, P2.5dB					
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	Р _{оит} (dBm)	Р _{оит} (W)	η₀ (%)	АМ/РМ (°)
0.9	0.80 + j1.38	6.36 - j0.32	20.5	47.0	49.8	60.2	-0.3
1.4	0.97 - j2.15	5.45 - j0.76	17.2	46.9	49.2	58.0	0.7
2.0	1.83 - j5.07	3.95 - j1.18	12.8	47.3	53.6	54.8	-3.0
2.5	2.01 - j8.91	4.33 - j2.30	13.2	48.0	63.1	56.5	-1.3
2.7	2.64 - j11.0	4.33 - j2.88	13.0	47.4	54.3	54.1	0.1
3.0	4.93 - j14.4	3.96 - j3.50	12.4	47.4	55.2	55.6	0.7
3.5	17.4 - j13.9	3.28 - j4.55	11.6	47.0	50.5	56.4	-4.6

		Maximum Drain Efficiency V _{DS} = 28 V, I _{DQ} = 130 mA, T _C = 25°C, P2.5dB							
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	Р _{оит} (dBm)	Р _{оит} (W)	η₀ (%)	AM/PM (°)		
0.9	0.72 + j0.58	12.35 +j8.87	22.7	43.9	24.6	70.2	-2.1		
1.4	0.71 - j2.61	7.30 + j5.46	19.9	44.5	28.4	70.5	0.1		
2.0	1.58 - j5.46	3.47 + j3.02	14.7	44.5	28.2	66.2	-9.5		
2.5	1.74 - j9.26	4.13 + j0.52	14.8	46.5	45.1	65.4	-5.3		
2.7	2.20 - j11.4	3.20 + j0.64	15.0	45.3	34.2	64.2	-6.0		
3.0	4.73 - j15.5	2.96 - j0.48	14.3	45.6	36.6	67.0	-3.4		
3.5	22.5 - j14.1	1.93 - j1.70	13.6	43.9	24.8	69.3	-20.1		

Impedance Reference



Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.

Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.

11. Load Impedance for optimum output power.

12. Load Impedance for optimum efficiency.

6

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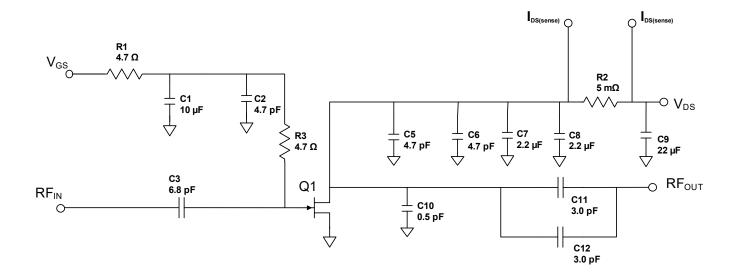
GaN Amplifier 50 V, 85 W DC - 3.5 GHz

MACOM

MACOM PURE CARBIDE

MAPC-A1101 Rev. V5

Evaluation Test Fixture and Recommended Tuning Solution: 3.45 - 3.55 GHz



Description

Parts measured on evaluation board (20-mil thick RO4350). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

Bias Sequencing Turning the device ON

- 1. Set V_{GS} to pinch-off (V_P).
- 2. Turn on V_{DS} to nominal voltage (50 V).
- 3. Increase V_{GS} until I_{DS} current is reached.
- 4. Apply RF power to desired level.

Turning the device OFF

- 1. Turn the RF power OFF.
- 2. Decrease V_{GS} down to V_P pinch-off.
- 3. Decrease V_{DS} down to 0 V.
- 4. Turn off V_{GS}.

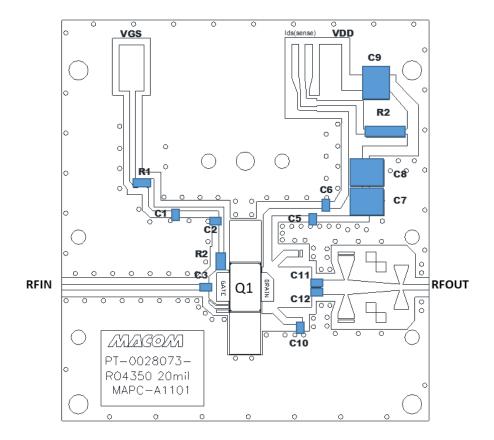
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MAPC-A1101

Rev. V5

Evaluation Test Fixture and Recommended Tuning Solution: 3.45 - 3.55 GHz

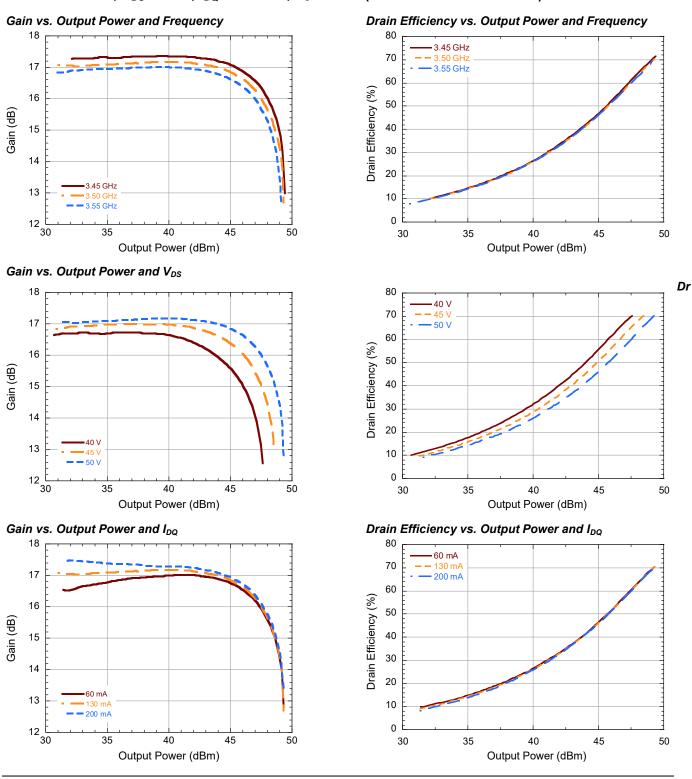


Reference Designator	Value	Tolerance	Manufacturer	Part Number		
C1	10 µF	+/- 10 %	Murata	GRM21BZ71C106KE15L		
C2, C5, C6	4.7 pF	+/- 0.1 pF	Murata	GQM2195C2E4R7BB12D		
C3	6.8 pF	+/- 0.1 pF	Murata	GQM2195C2E6R8BB12D		
C7, C8	2.2 µF	+/- 20%	Murata	KRM55TR72E225MH01L		
C9	22 µF	+/- 20%	Murata	KRM55WR72A226MH01K		
C10	0.5 pF	+/- 0.1 pF	Murata	GQM2195C2ER50BB12D		
C11, C12	3.0 pF	+/- 0.1 pF	Murata	GQM2195C2E3R0BB12D		
R2	5 mΩ	+/- 1%	Susumu	RL7520WT-R005-F		
R1, R3	4.7 Ω	+/- 1%	Panasonic	ERJ-8RQF4R7V		
Q1	MACON	/ GaN Power /	MAPC-A1101			
PCB	RO4350, 20 mil, 1 oz. Cu, Au Finish					

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Typical Performance Curves as Measured in the 3.45 - 3.55 GHz Evaluation Test Fixture: Pulsed⁴ 3.5 GHz, V_{DS} = 50 V, I_{DQ} = 130 mA, T_{C} = 25°C (Unless Otherwise Noted)

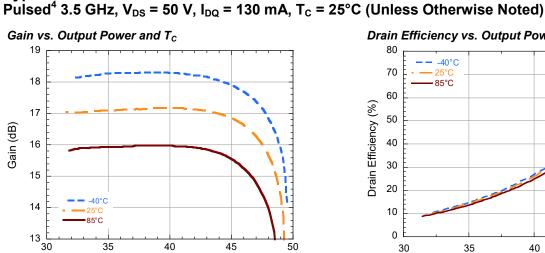
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MAPC-A1101 Rev. V5



Output Power (dBm)

Gain vs. Frequency, 2.5dB Gain Compression

16

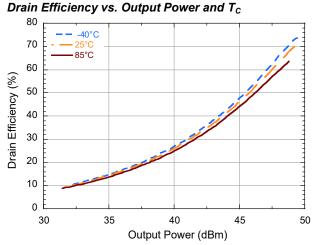
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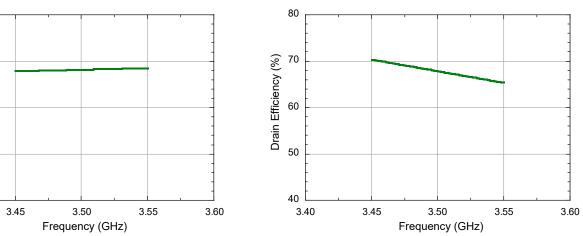
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3.40

Gain (dB) 14

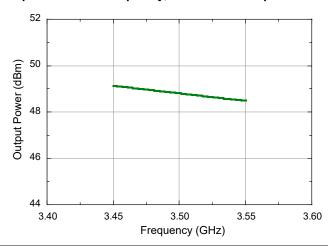


Drain Efficiency vs. Frequency, 2.5dB Gain Compression



Output Power vs. Frequency, 2.5dB Gain Compression

Typical Performance Curves as Measured in the 3.45 - 3.55 GHz Evaluation Test Fixture:



10

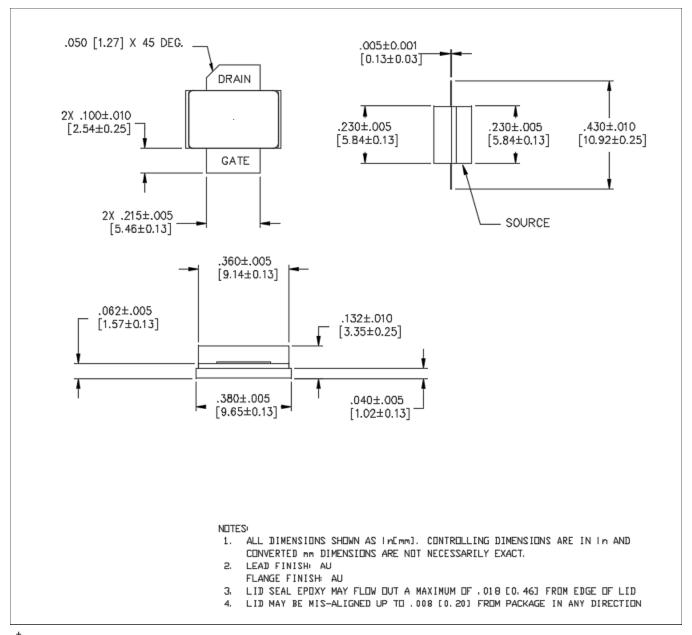
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MAPC-A1101

Rev. V5

Lead-Free AC-360S-2 Package Dimensions[†]



[†] Reference Application Note AN0004363 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.

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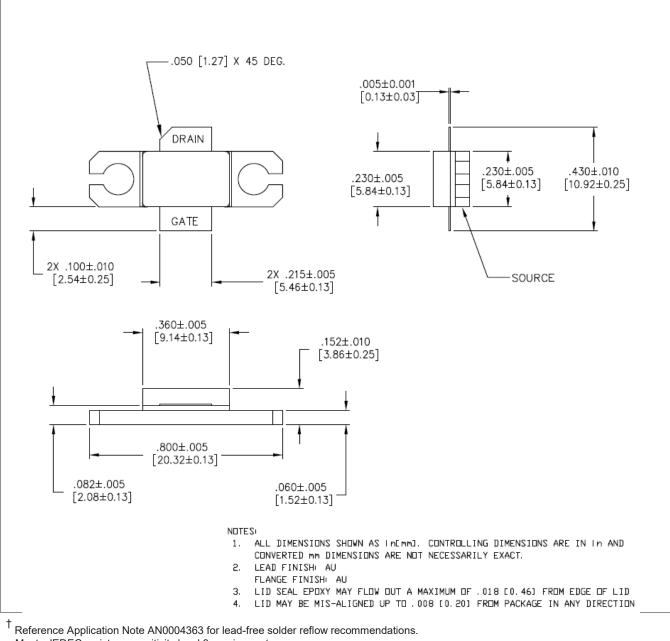


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MAPC-A1101

Rev. V5

Lead-Free AC-360B-2 Package Dimensions[†]



Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.

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